NSN 5961-01-398-2197

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-398-2197 **Inclosure Material:** Plastic or ceramic **Overall Length:** Between 0.165 inches and 0.195 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 0.30 amperes forward current, dc megahertz **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 unthreaded hole **Specification Data:** 81349-mil-s-19500/578 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No